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Part Number	2N4401
product family	TO-92 Plastic-Encapsulate Biploar Transistors
Product Polarity	NPN
SMD/ThroHole	Through Hole
VCEO	40V
VCBO	60V
VEBO	6.0V
Ic	
PC	600mW
HFE(min)	80
@Ic	10mA
@VCE	1.0V
ICBO	
IEBO	
VCE(sat)	0.4V
VBE(sat)	0.95V
ft	250MHz
nf	
TON_max	
Package Qty	Bulk: 1k/Bag,, 100K/Ctn; T/B: 2K/Ammo Box , 20K/Ctn;

Green/Pb Free/RoHS/REACH

FAQ

[Soldering Profile](#)

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[Ordering Information](#)

[Certification of REACH Compliance](#)


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[Deca certification\(DecaBDE\)](#)

[MCC's EU RoHS and Green \(Halogen & Antimony Free\)](#)

[Parts List](#)

[REACH SVHC Test Report](#)





Micro Commercial Components

2N4401

NPN General Purpose Amplifier

Features

- Through Hole Package
- Capable of 600mWatts of Power Dissipation
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0 and MSL rating 1
- Marking: Type number
- Lead Free Finish/Rohs Compliant ("P" Suffix designates Compliant. See ordering information)

Electrical Characteristics @ 25°C Unless Otherwise Specified

Symbol	Parameter	Min	Max	Units
OFF CHARACTERISTICS				
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage* ($I_C=1.0mA$, $I_B=0$)	40		Vdc
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage ($I_C=10mA$, $I_E=0$)	60		Vdc
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage ($I_E=0.1mA$, $I_C=0$)	6.0		Vdc
I_{BL}	Base Cutoff Current ($V_{CE}=35Vdc$, $V_{BE}=0.4Vdc$)		0.1	μA
I_{CEX}	Collector Cutoff Current ($V_{CE}=35Vdc$, $V_{BE}=0.4Vdc$)		0.1	μA

ON CHARACTERISTICS

h_{FE}	DC Current Gain* ($I_C=0.1mA$, $V_{CE}=1.0Vdc$) ($I_C=1.0mA$, $V_{CE}=1.0Vdc$) ($I_C=10mA$, $V_{CE}=1.0Vdc$) ($I_C=150mA$, $V_{CE}=1.0Vdc$) ($I_C=500mA$, $V_{CE}=1.0Vdc$)	20 40 80 100 40	300	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage ($I_C=150mA$, $I_B=15mA$) ($I_C=500mA$, $I_B=50mA$)		0.4 0.75	Vdc
$V_{BE(sat)}$	Base-Emitter Saturation Voltage ($I_C=150mA$, $I_B=15mA$) ($I_C=500mA$, $I_B=50mA$)	0.75	0.95 1.2	Vdc

SMALL-SIGNAL CHARACTERISTICS

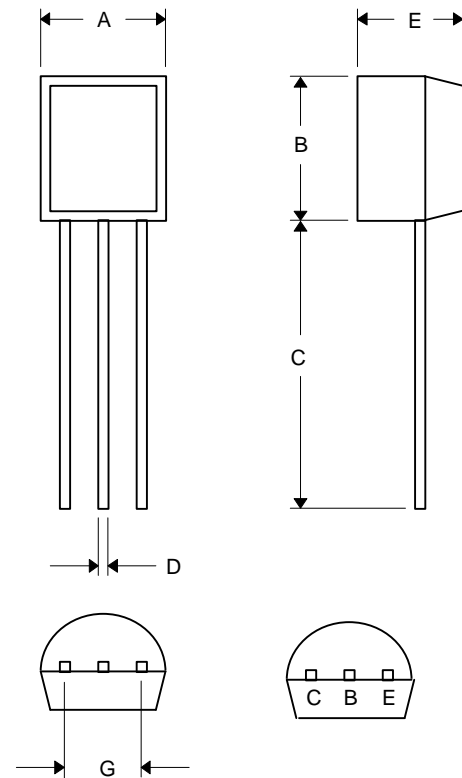
f_T	Current Gain-Bandwidth Product ($I_C=20mA$, $V_{CE}=10Vdc$, $f=100MHz$)	250		MHz
C_{cb}	Collector-Base Capacitance ($V_{CB}=5.0Vdc$, $I_E=0$, $f=100kHz$)		6.5	pF
C_{eb}	Emitter-Base Capacitance ($V_{BE}=0.5Vdc$, $I_C=0$, $f=100kHz$)		30.0	pF

SWITCHING CHARACTERISTICS

t_d	Delay Time	$(V_{CC}=30Vdc, V_{BE}=0.2Vdc$	15	ns
t_r	Rise Time	$I_C=150mA, I_{B1}=15mA$)	20	ns
t_s	Storage Time	$(V_{CC}=30Vdc, I_C=150mA$	225	ns
t_f	Fall Time	$I_{B1}=I_{B2}=15mA$)	30	ns

*Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2.0\%$

TO-92



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.170	.190	4.33	4.83	
B	.170	.190	4.30	4.83	
C	.550	.590	13.97	14.97	
D	.010	.020	0.36	0.56	
E	.130	.160	3.30	3.96	
G	.010	.104	2.44	2.64	



Micro Commercial Components

Ordering Information

Device	Packing
(Part Number)-AP	Ammo Packing;2Kpcs/AmmoBox
(Part Number)-BP	Bulk;1Kpcs/Bag